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High power acousto-optical Q-switched Tm:YLF-pumped Ho:GdVO₄ laser

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ABSTRACT

A high power acousto-optical Q-switched Ho:GdVO₄ laser at 2.05 μ m pumped by a diodepumped VBG-locked Tm:YLF laser at 1.94 μ m is demonstrated in this paper. The maximum average output power of 10.3 W at pulse repetition rate of 10 kHz was obtained with the absorbed pump power of 34.9 W, corresponding to a slope efficiency of 36.8%. The minimum pulse width of 5.8 ns was obtained, corresponding to a peak power of 177.6 kW. The laser operated at a single mode (TEM₀₀) with a beam quality factor of M_x² of 1.3 and M_y² of 1.2 at maximum output level.

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1. Introduction

Pulsed solid-state lasers emitting in the nominally eye-safe 2 μ m spectral region are very attractive for various technical applications in lidar, material processing, and mid-infrared generation via pumping optical parametric oscillators (OPOs) [1–3]. The rare-earth-ion thulium (Tm³⁺) and holmium (Ho³⁺) co-doping materials are commonly used to obtain the 2 μ m laser. Unfortunately, due to the large upconversion loss and re-absorption loss, these lasers are difficult to achieve high performance at room temperature. In contrast, in-band pumping of the Ho system offers many advantages such as low quantum defect, low upconversion losses, and reduced sensitivity of gain versus temperature. In addition, Ho-doped solid-state lasers with long upper laser level lifetime are particularly attractive for Q-switched operation.

Among numerous hosts, gadolinium vanadate $(GdVO_4)$ crystals doped with various ions represent a promising new material for diode-pumped Tm and Tm, Ho co-doped lasers. The GdVO₄ crystal has a large thermal conductivity (11.7 W/mK) which makes it favorable to cool the crystal efficiently. The thermal conductivity of GdVO₄ is more than a factor of two higher than that of YVO₄ and is even higher than that of YAG. Recently, continuous wave (CW) and Q-switched laser performances of Tm:GdVO₄ and Tm, Ho:GdVO₄ crystals were widely investigated [4–7]. For singly Ho:GdVO₄ lasers, using a Tm-fiber laser as the pump source, our group developed the its output power as high as 10 W-level [8,9]. However, the Tm-fiber with free polarization was used in above works, the output power of Ho:GdVO₄ laser is fluctuated wildly, which caused by polarization change of Tm-fiber when fiber is moving.

In this paper, we used a diode-pumped VBG-locked Tm:YLF laser with linear polarization as the pump source, investigated the room temperature CW and actively Q-switched performances of Ho:GdVO₄ laser. When the absorbed pump power is 34.9 W, the maximum output power of 11.5 W and 10.3 W were obtained with CW and Q-switched mode, respectively. At

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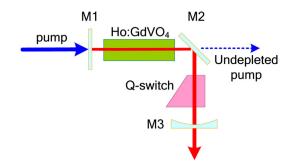


Fig. 1. Diagram of the experimental setup.

the repetition rate of 10 kHz, the minimum pulse width of 5.8 ns was obtained, corresponding to a peak power of 177.6 kW. The output beam had quality of M^2 factor with M_x^2 of 1.3 and M_y^2 of 1.2 at maximum output level.

2. Experimental setup

The experimental setup is schematically shown in Fig. 1. The dimension of *a*-cut Ho:GdVO₄ crystal with doped concentration of 1.0 at.% is 4 mm × 4mm (in cross section) ×20 mm (in length). The two end faces of the crystal were antireflection coated at both pump wavelength of 1.94 μ m(R<0.5%) and lasing wavelength of 2 μ m (R<0.3%). The Ho:GdVO₄ crystal was sandwiched between two water-cooled copper heat sinks using 0.1-mm-thick indium foil. The temperature of the cooling water for the laser crystal is controlled at 20 °C. A homemade diode-pumped VBG-locked Tm:YLF laser with output power of 50 W was used as the pump source. Its output wavelength and linewidth are 1940 nm and 0.2 nm, respectively. The pump beam diameter was measured to be 500 μ m in the Ho:GdVO₄ crystal. We also measured that the single-pass absorptions of Ho:GdVO₄ crystal is 74% at pump wavelength.

A L-shaped resonator with physical cavity length of about 100 mm was used for the Ho:GdVO₄ laser. The cavity mirror M1 was flat with high reflectivity at 2 μ m and high transmission at 1.94 μ m. The flat 45° dichroic mirror M2 had high transmission for the pump light and high reflectivity at 2 μ m. The output coupling M3 was plane-concave with the radius of curvature of 200 mm and transmittance of 40%. An AR-coated quarts acousto-optic (AO) switch (Model: QSG41-2) with acoustic aperture of 1.1 mm was used for Q-switched operation. The length of Q-switch crystal was 35 mm. The radio frequency (RF) was 41 MHz, and the RF power was 20 W. The modulation loss is greater than 45%, which is adequate to hold off the laser actions.

3. Experimental results and discussion

Firstly, we investigated the CW output performance of Ho:GdVO₄ laser, as shown in Fig. 2. The threshold pump power was 6.78 W. The maximum output power of 11.5 W was obtained with absorbed pump power of 34.9 W. With respect to the absorbed pump power, the slope efficiency was 40.2%, corresponding to the optical-to-optical efficiency of 33.0%. Secondly, in the case of Q-switched mode, at the pulse repetition rate of 10 kHz, the maximum average output power 10.3 W was achieved at same pump power, corresponding to the slope efficiency of 36.8% and optical-to-optical efficiency of 29.5%. The output spectrum of CW Ho:GdVO₄ laser was measured by a wavemeter (Bristol 721A), as shown in Fig. 2. The output wavelength was centered at 2047.9 nm. The full width at half-maximum linewidth was 0.2 nm.

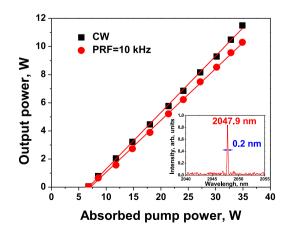


Fig. 2. The output characteristics of Ho:GdVO₄ laser. Insert, the output spectrum of CW Ho:GdVO₄ laser.

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